Provisional Data

Rectifier Diode
Types W9830TJ120 to W9830TJ150
Development Type No.: WX375TJ150

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1200-1500	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1300-1600	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T_{sink}=55°C, (note 2)	9830	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 2)	7605	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 3)	4075	A
$I_{F(RMS)M}$	Nominal RMS forward current, T_{sink}=25°C, (note 2)	17480	A
$I_{F(d.c.)}$	D.C. forward current, T_{sink}=25°C, (note 4)	15450	A
I_{FSM}	Peak non-repetitive surge t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	72.0	kA
I_{FSM2}	Peak non-repetitive surge t_p=10ms, $V_{rm} \leq$10V, (note 5)	80.0	kA
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	25.9×10^6	A^2s
I^2t	I^2t capacity for fusing t_p=10ms, $V_{rm} \leq$10V, (note 5)	32.0×10^6	A^2s
$T_{j\,op}$	Operating temperature range	-40 to +190	°C
T_{stg}	Storage temperature range	-55 to +190	°C

Notes:-
1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
4) Double side cooled.
5) Half-sinewave, 190°C T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	0.95	I_{FM}=6800A	V
V_{FM}	Maximum peak forward voltage	-	-	1.24	I_{FM}=17000A	V
V_{T0}	Threshold voltage	-	-	0.67	Valid from 2000A to 6000A	V
r_T	Slope resistance	-	-	0.043		$m\Omega$
I_{RRM}	Peak reverse current	-	-	100	Rated V_{RRM}	mA
Q_{rr}	Recovered charge	-	3700	4250	I_{TM}=2000A, t_p=2000µs, di/dt=10A/µs, V_r=100V	µC
Q_{ra}	Recovered charge, 50% Chord	-	3000	-		µC
I_{rm}	Reverse recovery current	-	200	-		A
t_{rr}	Reverse recovery time, 50% chord	-	30	-		µs
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.008	Double side cooled	K/W
		-	-	0.013	Anode side cooled	K/W
		-	-	0.020	Cathode side cooled	K/W
F	Mounting force	60	-	70	Note 2	kN
W_t	Weight		1.15			Kg

Notes:-

1) Unless otherwise indicated T$_j$=190°C.
2) For other clamp forces, please consult factory.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
12	1200	1300	720
15	1500	1600	900

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

    5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^{\;2} + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\,\max} - T_K$$

Where V_{T0}=0.67V, r_T=0.043mΩ,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.00866	0.00847	0.00832	0.00800
Square wave Cathode Side Cooled	0.02118	0.02101	0.02086	0.02000
Sine wave Double Side Cooled	0.00855	0.00837	0.00813	
Sine wave Cathode Side Cooled	0.02108	0.02091	0.02068	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;
(i)   the well established V_{T0} and r_T tangent used for rating purposes and
(ii)   a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients		190°C Coefficients
A	0.798634	A	0.266920
B	2.802491×10^{-4}	B	5.121623×10^{-2}
C	4.077433×10^{-6}	C	1.713520×10^{-5}
D	4.359019×10^{-3}	D	1.404316×10^{-3}

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}} \right)$$

Where $p = 1$ to n, n is the number of terms in the series and:

    t = Duration of heating pulse in seconds.

    r_t = Thermal resistance at time t.

    r_p = Amplitude of p_{th} term.

    τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled			
Term	1	2	3	4
r_p	3.81150×10⁻³	1.89558×10⁻³	1.71360×10⁻³	5.24282×10⁻⁴
τ_p	1.01434	0.34872	0.08992	0.01065

Term	1	2	3
r_p	0.01653	3.37618×10⁻³	5.93598×10⁻⁴
τ_p	5.31595	0.15120	0.01207

6.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig. 1
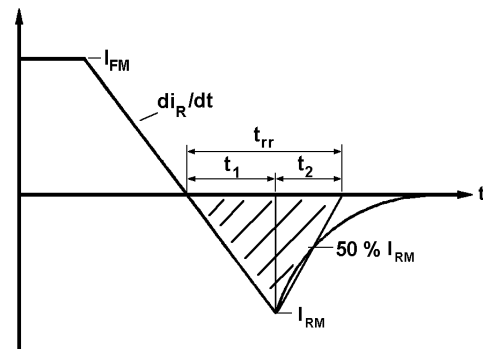
Fig. 1

(ii) Q_{rr} is based on a 150µs integration time i.e.

$$Q_{rr} = \int_0^{150\,\mu s} i_{rr}.dt$$

(iii)

$$K\ Factor = \frac{t_1}{t_2}$$

Curves

Figure 1 – Forward characteristics of Limit device

W9830TJ120-150
Issue A2

190°C   25°C

Instantaneous forward current - I_{FM} (A)

Maximum instantaneous forward voltage - V_{FM} (V)
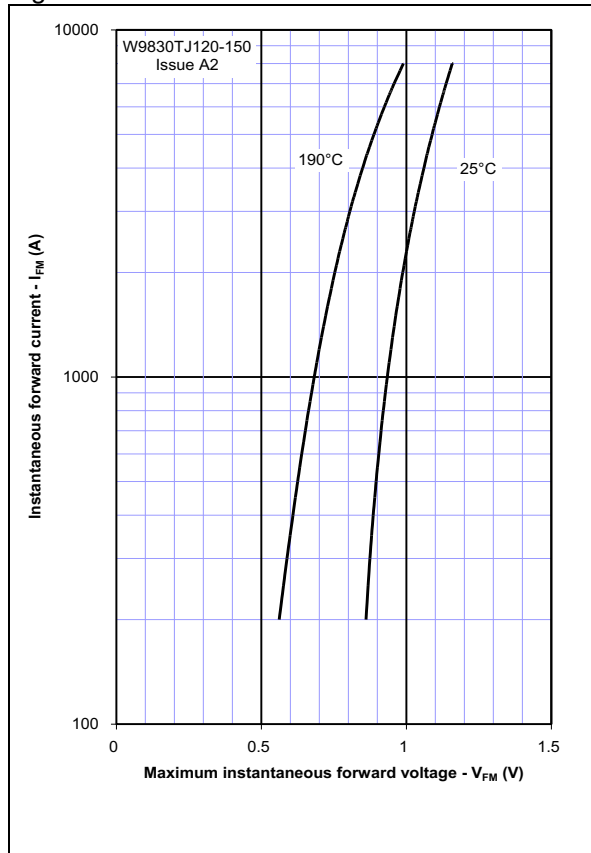
Figure 2 – Transient thermal impedance

W9830TJ120-150
Issue A2

KSC
ASC
DSC

Thermal impedance (K/W)

Time (s)
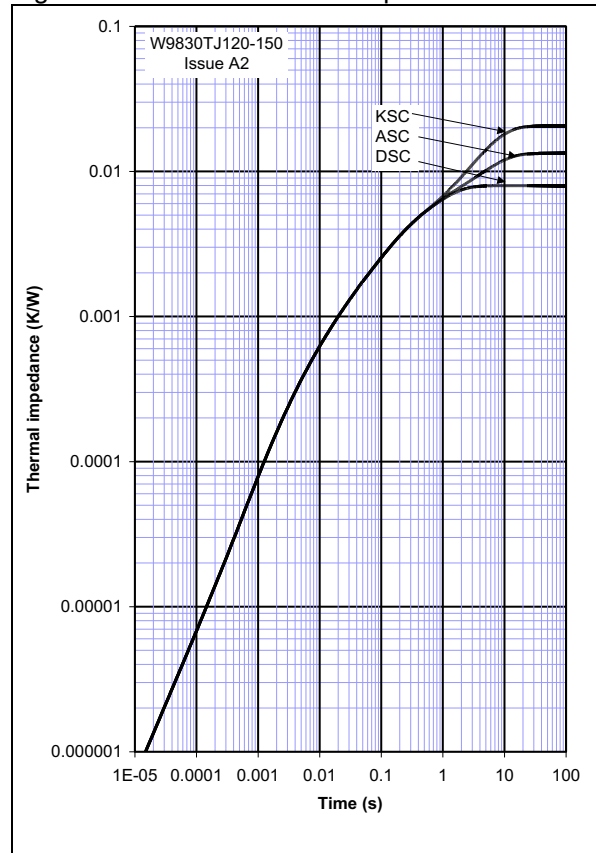
Figure 3 – Maximum Surge Rating

W9830TJ120-150
Issue A2

T_j (initial) = 190°C

I^2t: $V_R \leq 10V$

I^2t: $V_R = 60\%$ V_{RRM}

I_{FSM}: $V_R \leq 10V$

I_{FSM}: $V_R = 60\%$ V_{RRM}

Total peak half sine surge current - I_{FSM} (A)

Maximum I^2t (A^2s)

Duration of surge (ms)   Duration of surge (cycles @ 50Hz)
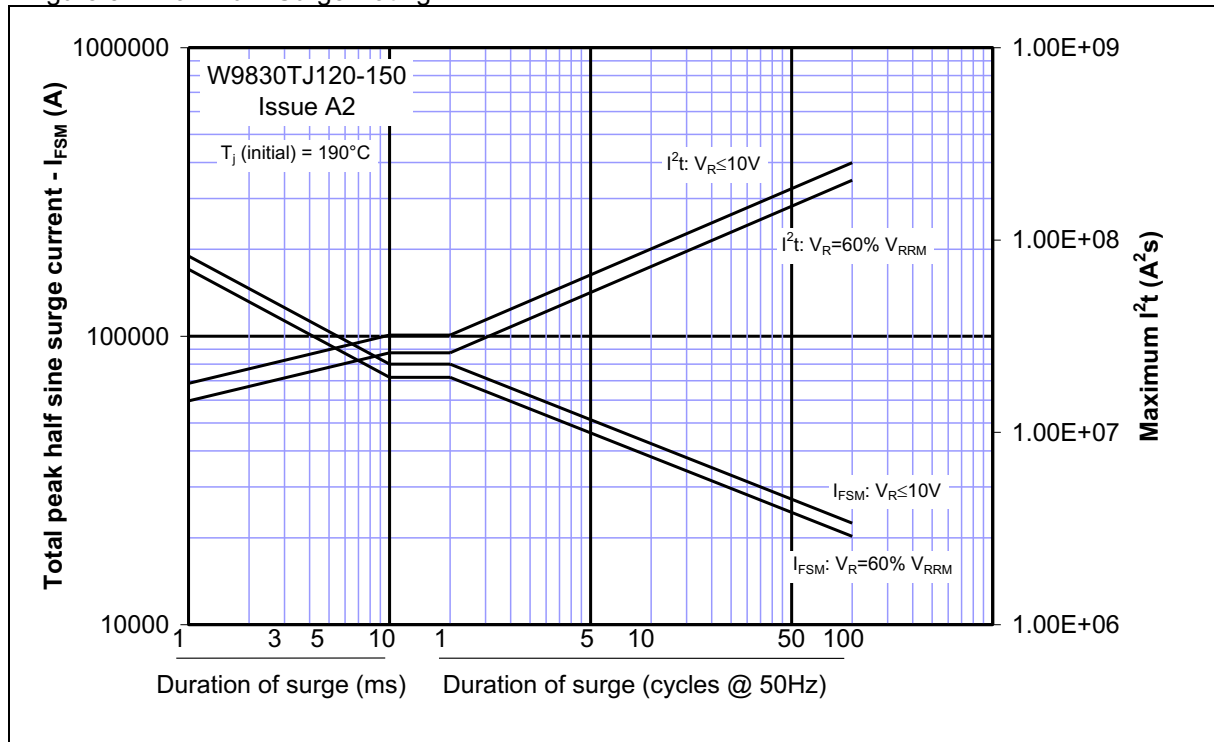
Figure 4 – Total recovered charge, Q_{rr}
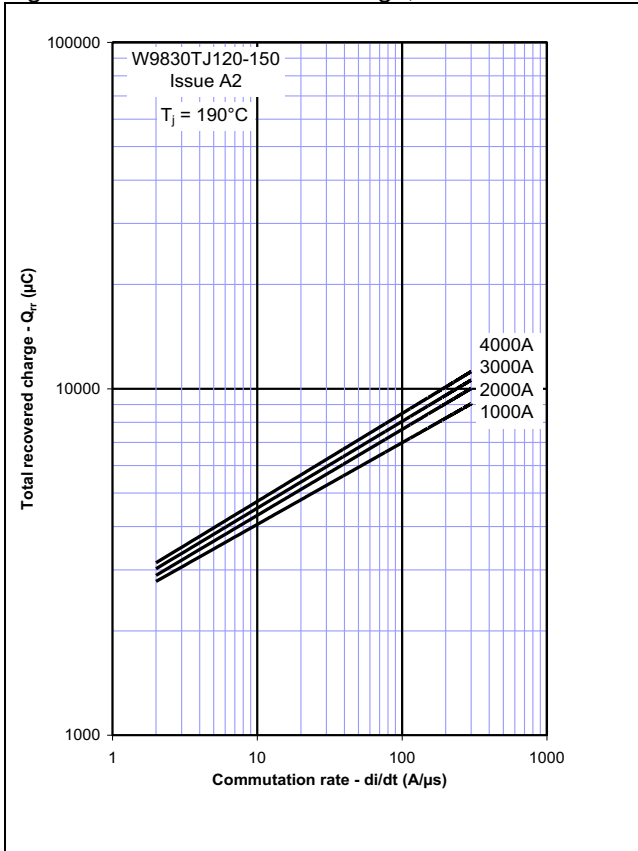
Figure 5 – Recovered charge, Q_{ra} (50% chord)
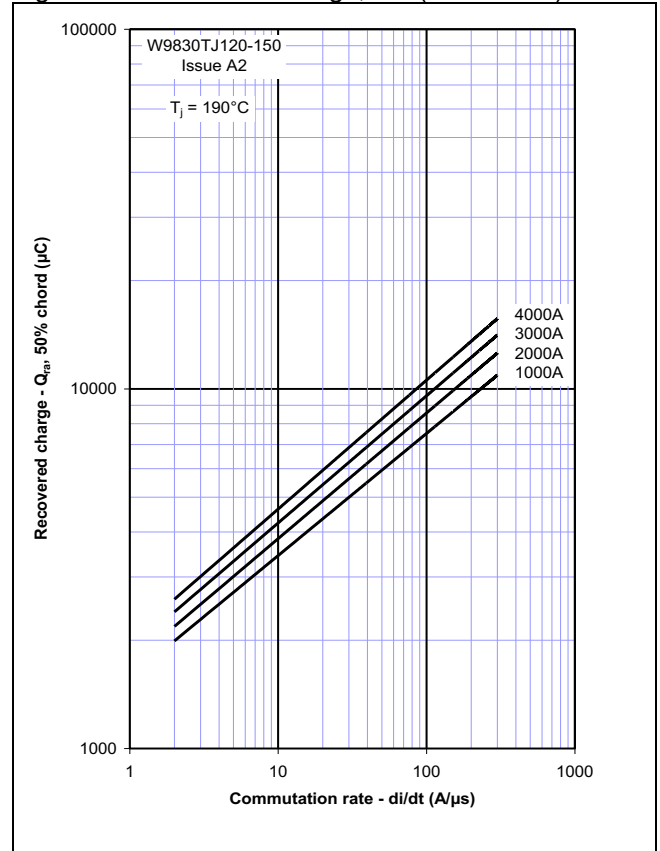
Figure 6 – Peak reverse recovery current, I_{rm}
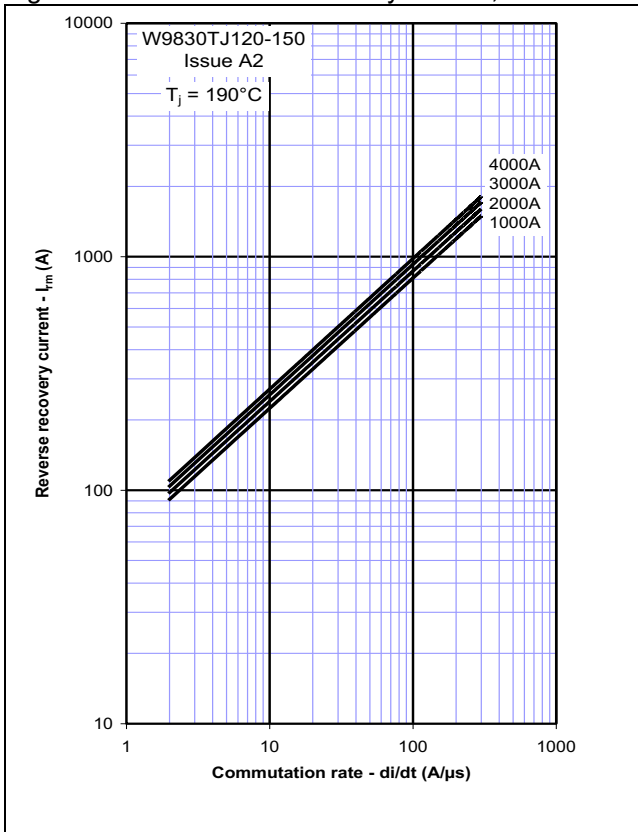
Figure 7 – Maximum recovery time, t_{rr} (50% chord)
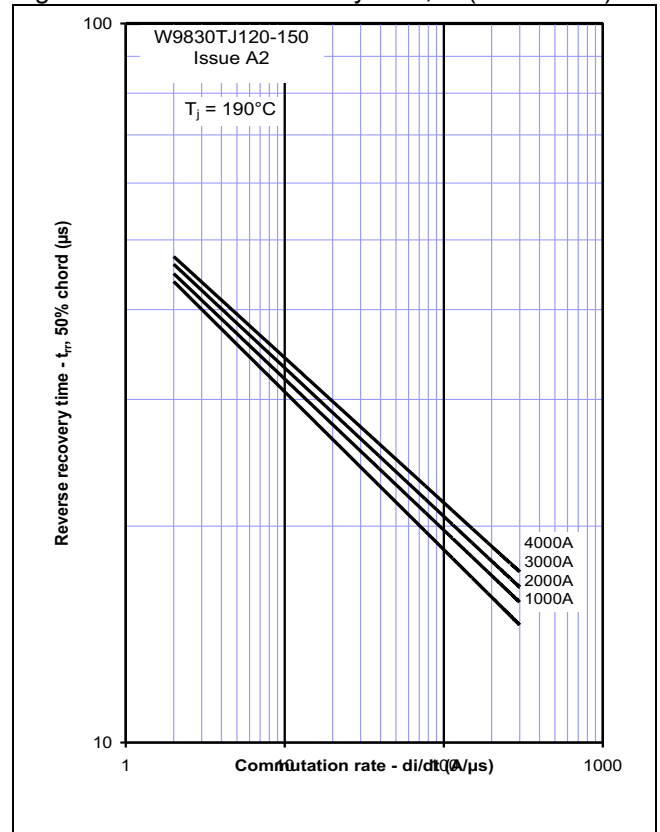
Figure 8 – Forward current vs. Power dissipation – Double Side Cooled
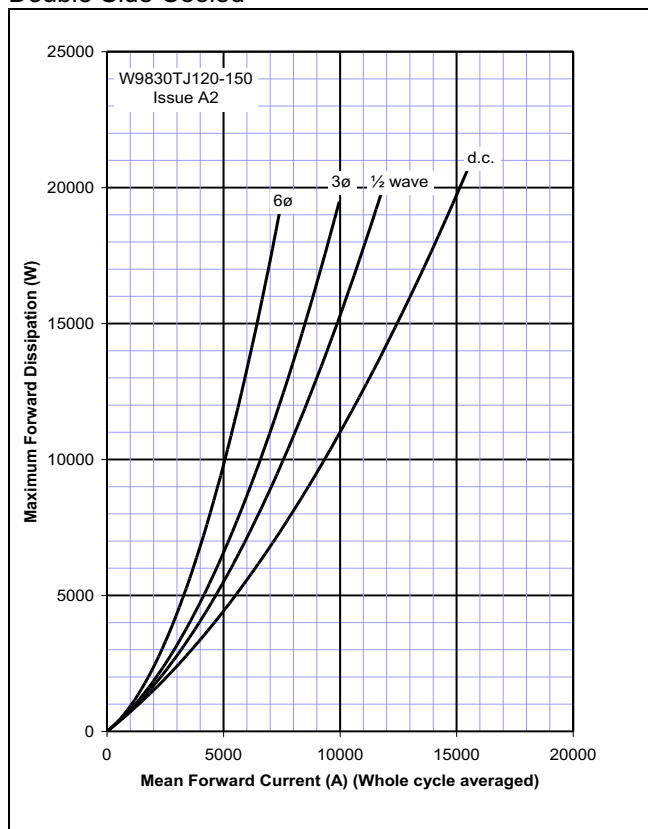
Figure 9 – Forward current vs. Heatsink temperature – Double Side Cooled
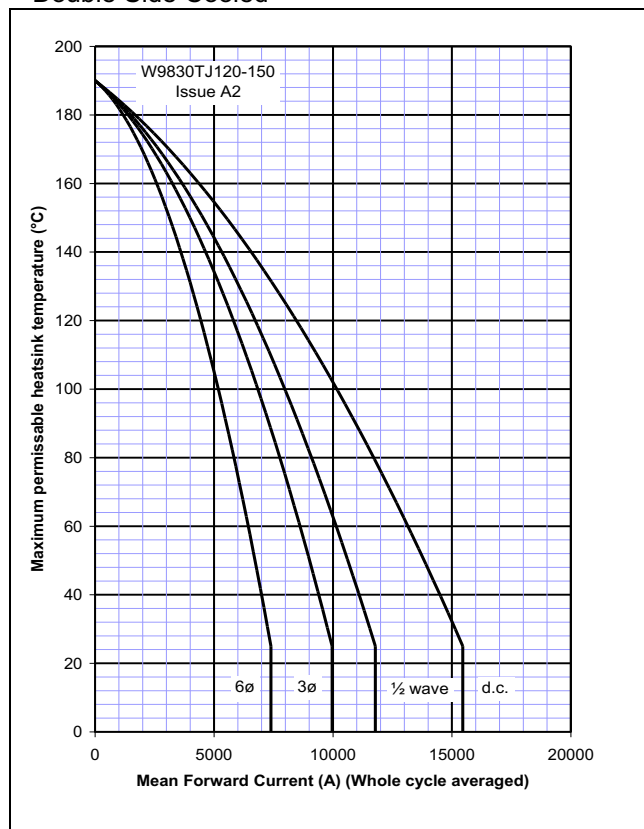

Figure 10 – Forward current vs. Power dissipation – Cathode Side Cooled
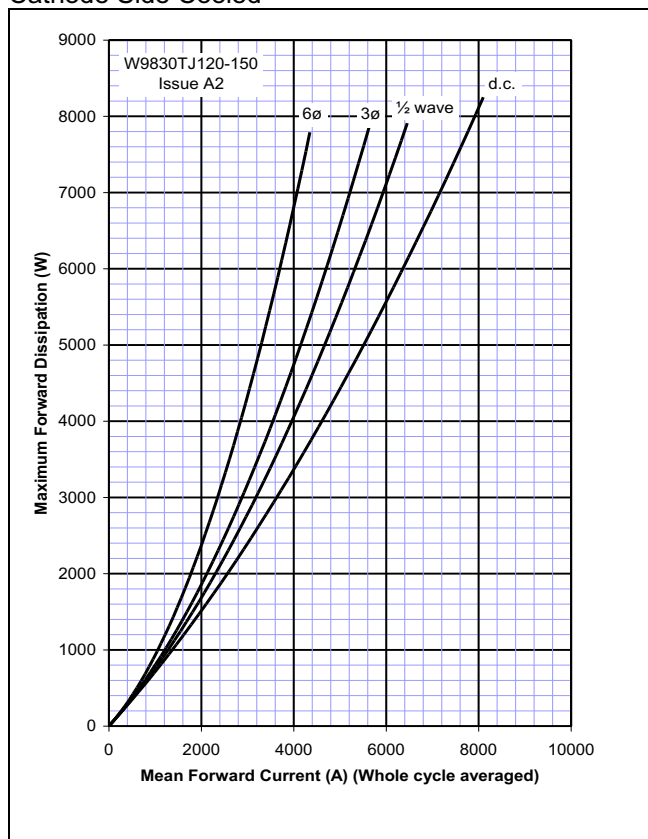
Figure 11 – Forward current vs. Heatsink temperature – Cathode Side Cooled
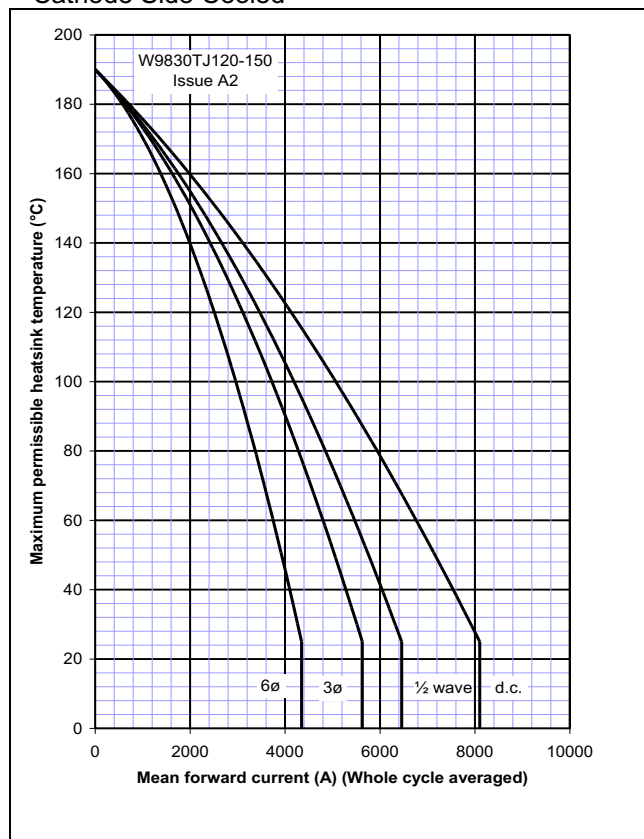
Outline Drawing & Ordering Information

Ø3.6/3.5 × 2 MIN
DEPTH 2-HOLES, ONE
IN CATHODE AND
ONE IN ANODE.

Ø112 MAX
Ø75
1 MIN
26±0.5 COMPRESSED HEIGHT
1 MIN
Ø75

CREEP PATH OVER
CONVOLUTIONS =
38 MIN.

100A368
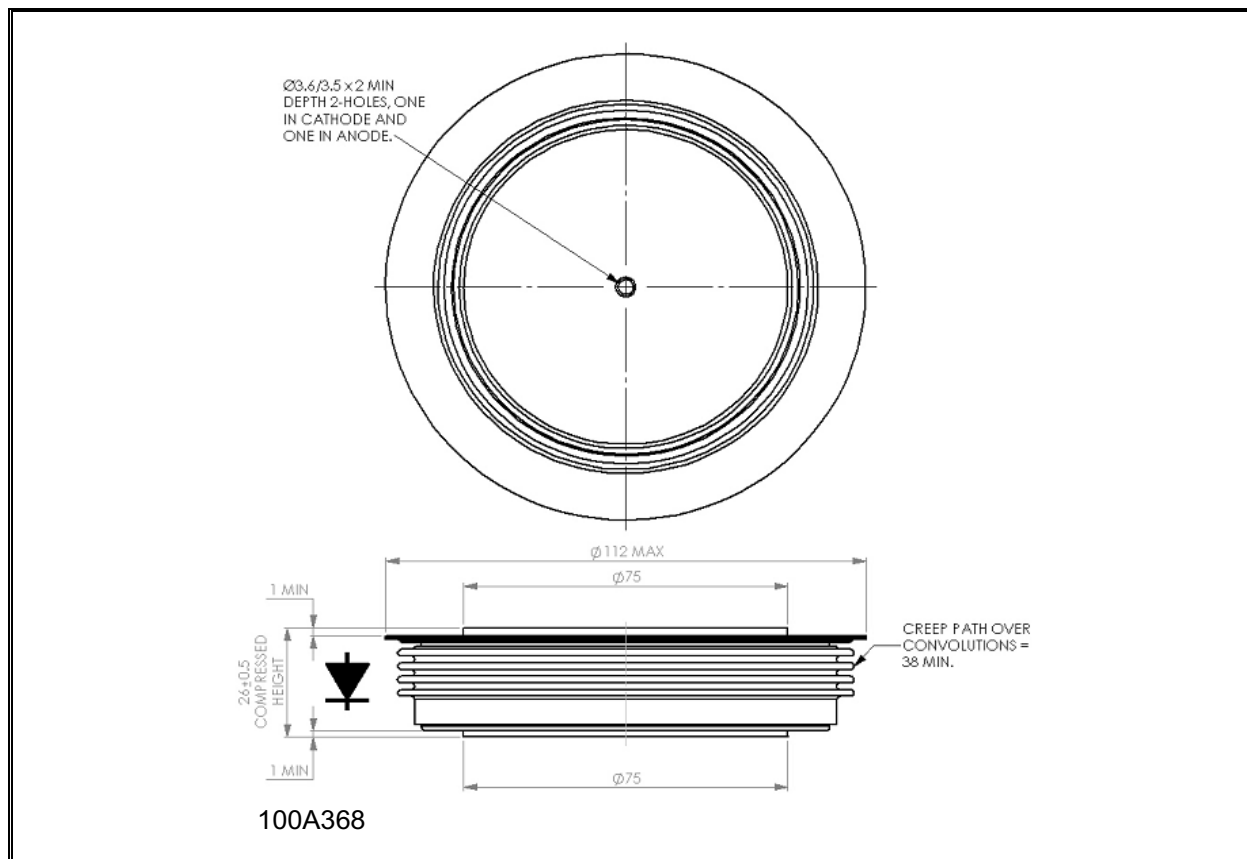
ORDERING INFORMATION		(Please quote 10 digit code as below)	
W9830	**TJ**	**♦♦**	**0**
Fixed Type Code	Fixed Outline Code	Voltage code V$_{RRM}$/100 12-15	Fixed code

Order code: W9830TJ150 – 1500V V$_{RRM}$, 26mm clamp height capsule.